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Appl. No. 10/646,206

Preliminary Amdt. dated September 24, 2004

Amendments to the Abstract:

Amend the Abstract as follows:

Abstract of the Disclosure:

A semiconductor product has an anti-reflective coating layer covering a semiconductor substrate. The ARC anti-reflective component layer is formed of a matrix substance and of nanocrystalline particles of another material than the matrix substance. The nanocrystalline particles absorb light via the quantum size effect, that is, the novel kind of ARC anti-reflective component layer is an absorbing ARC anti-reflective component layer.